

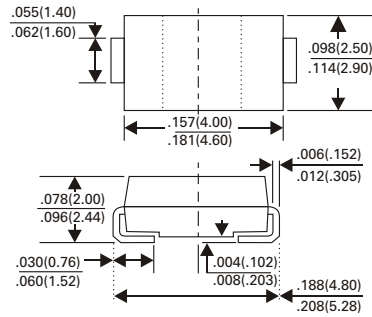
# US2AA thru US2MA

## SURFACE MOUNT REVERSE VOLTAGE 50 TO 1000 VOLTS

### ULTRA FAST RECTIFIERS FORWARD CURRENT - 2.0 AMPERES



SMA/DO-214AC



Dimensions in inches and (millimeters)

### FEATURES

- For surface mounted applications
- Low profile package
- Built-in strain relief
- Easy pick and place
- Ultrafast recovery times for high efficiency
- Plastic package has Underwriters Laboratory Flammability classification 94V-0
- Glass passivated junction
- High temperature soldering  
260°C/10seconds at terminals

### MECHANICAL DATA

Case : JEDEC DO-214AC molded plastic  
 Terminals : Solder plated, solderable per MIL-STD-750, Method 2026  
 Polarity : Indicated by cathode band  
 Standard Packaging : 12mm tape (ELA-481)  
 Weight : 0.064grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified  
 Single phase, half wave, 60Hz, resistive or inductive load  
 For capacitive load, derate current by 20%

	SYMBOL	US2AA	US2BA	US2DA	US2FA	US2GA	US2JA	US2KA	US2MA	UNITS
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	200	300	400	600	800	1000	Volts
Maximum RMS Voltage	$V_{RMS}$	35	70	140	210	280	420	560	700	Volts
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	300	400	600	800	1000	Volts
Maximum Average Forward Rectified Current @ $T_L = 100^\circ C$	$I_{(AV)}$	2.0								Amps
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC Method) $T_A = 55^\circ C$	$I_{FSM}$	50								Amps
Maximum Instantaneous Forward Voltage at 2.0A DC	$V_F$	1.0			1.3		1.7			Volts
Maximum DC Reverse Current @ $T_A = 25^\circ C$ at Rated DC Blocking Voltage @ $T_A = 100^\circ C$	$I_R$	5.0 100								$\mu A$
Typical Junction Capacitance (NOTE 2)	$C_J$	50					30			pF
Maximum Reverse Recovery Time (NOTE 1) $T_J = 25^\circ C$	$T_{RR}$	50					75			nS
Maximum Thermal Resistance (NOTE 3)	$T_J$	-55 to +150								$^\circ C$
Operating and Storage Temperature Range	$T_J$ $T_{STG}$	-55 to +150								$^\circ C$

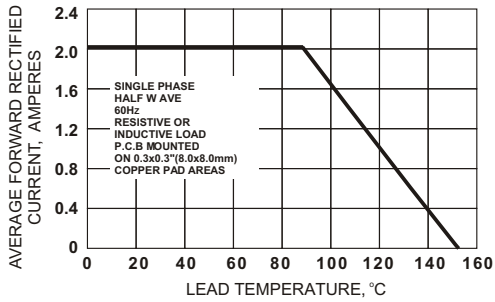
- NOTES :
1. Reverse Recovery Test Conditions  $I_F = 5A$ ,  $I_R = 1A$ ,  $I_{RR} = 0.25A$
  2. Measured at 1 MHz and applied reverse Voltage of 4.0VDC
  3. Measured on P.C.Board with 0.2" x 0.2" (5mmX5mm) Copper Pad Area.

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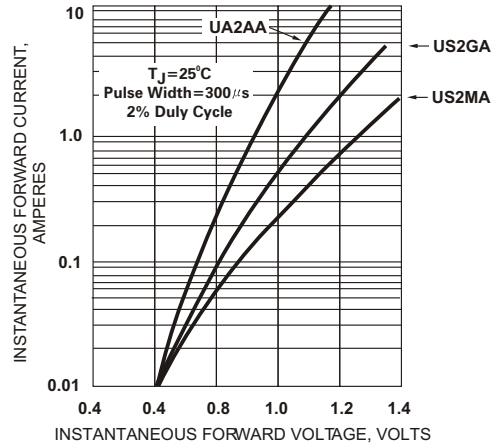
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### RATINGS AND CHARACTERISTIC CURVES US2AA THRU US2MA

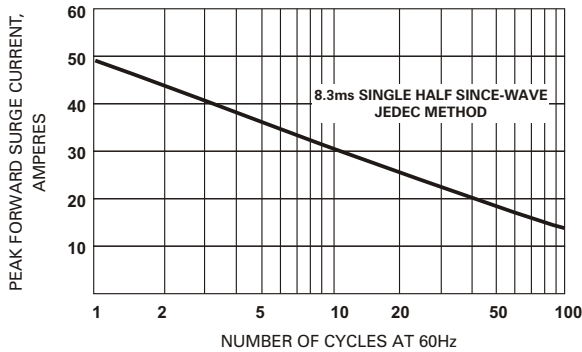
**Fig. 1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT**



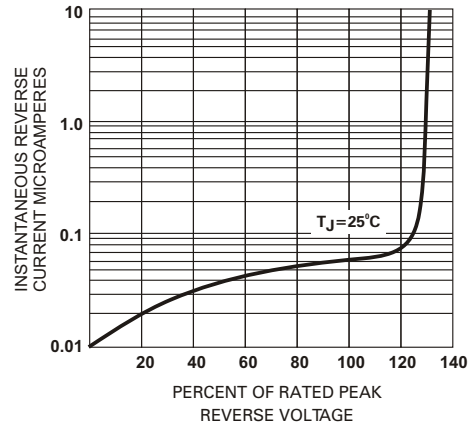
**Fig. 2 - TYPICAL FORWARD CHARACTERISTICS PER ELEMENT**



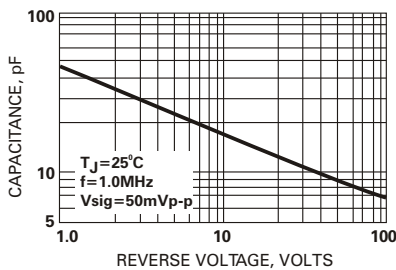
**Fig. 3 - MAXIMUM FORWARD SURGE CURRENT**



**Fig. 4 - TYPICAL REVERSE CHARACTERISTICS**



**FIG. 5 - TYPICAL JUNCTION CAPACITANCE PER BRIDGE ELEMENT**



**Fig. 6 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM**

